

SPOC™ Wire Guard

Features

- High-side power switch with diagnosis and embedded protection
- Daisy chain capable 24 bit SPI with CRC
- Embedded I<sup>2</sup>t wire and system protection
- Capacitive load switching mode
- Low operating current (idle mode) for active supply during parking
- ISO 26262 safety element out of context for safety requirements up to ASIL D

Potential applications

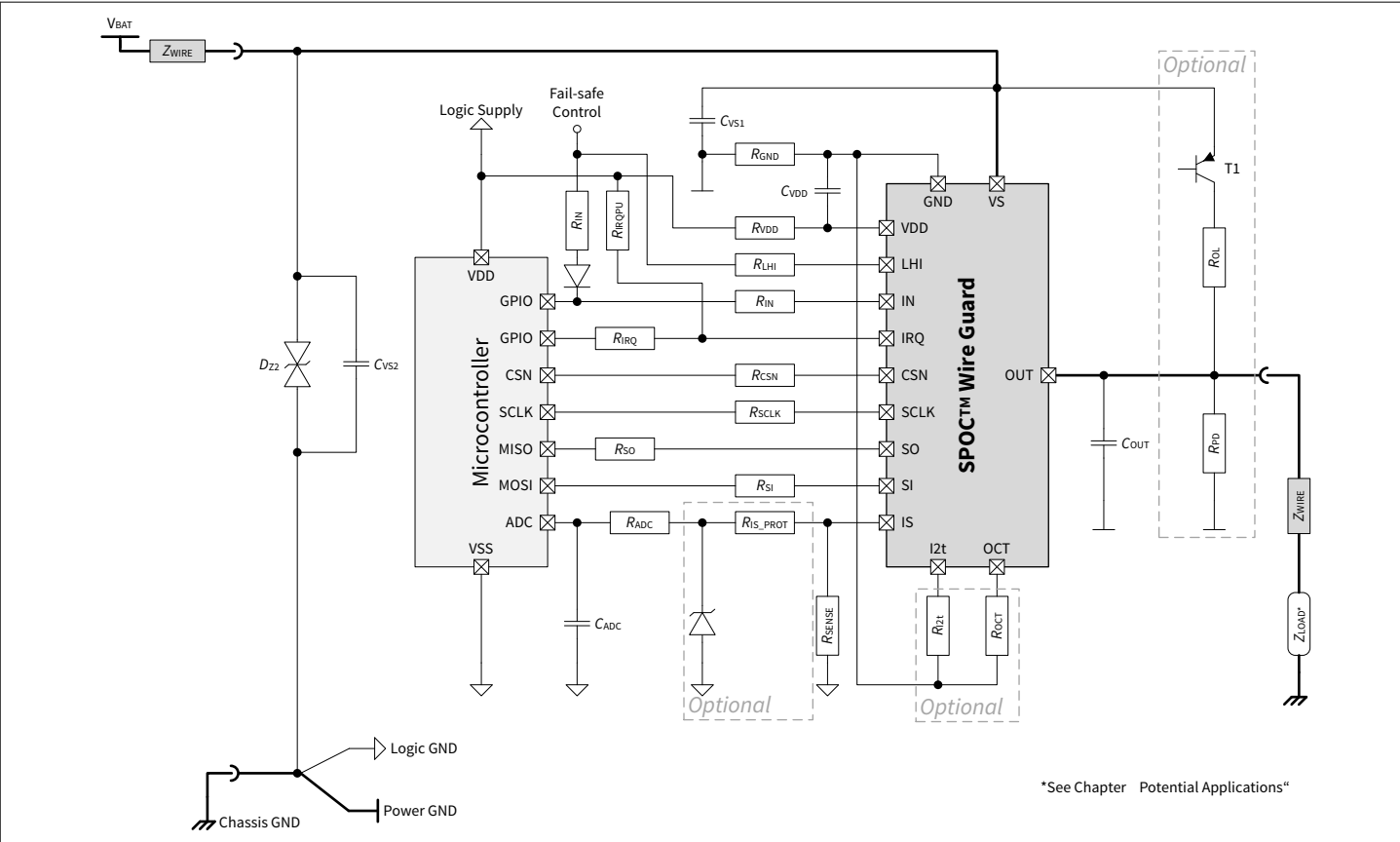
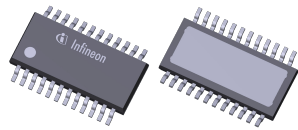
- Fail operational power supply
- Fuse and relay replacement in 12 V power distribution
- ECU main switch
- Active supply during parking mode

Product validation

Qualified for automotive applications. Product validation according to AEC-Q100, Grade 1.

Description

The SPOC™ Wire Guard is a smart high-side power switch with SPI as digital interface. The device is suitable for applications driving loads up to a nominal current of 27.3 A and supporting inrush currents. In addition to standard protection and standard diagnosis functions, the device offers selectable overcurrent protection, selectable I<sup>2</sup>t protection, idle mode, fail safe mode, limp home mode, and enhanced diagnosis via the digital interface.



\*See Chapter Potential Applications"

| Package     | Marking    |
|-------------|------------|
| PG-TSDSO-24 | S0014SWPI1 |



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## 1 Product description

### Basic features

- High-side power switch with diagnosis and embedded protection
- Daisy chain capable 24 bit SPI with CRC
- 3.3 V and 5 V compatible logic pins
- Low operating current (idle mode) for active supply during parking
- Idle mode with indication pin for microcontroller wake-up
- Capacitive load switching mode
- Reverse ON for low power dissipation in reverse polarity
- Switch-ON capability while inverse current condition (Inverse ON)
- Optimized for high immunity against electromagnetic interference (EMI)
- Green product (RoHS compliant)

### Protection features

- Configurable restart control
- Absolute and dynamic temperature limitation
- Overcurrent protection with selectable overcurrent threshold
- Undervoltage shutdown
- Configurable integrated I<sup>2</sup>t function for system protection
- Overvoltage protection with external components

### Diagnosis features

- Proportional load current sense
- Proportional chip temperature measurement
- Open load in ON and OFF state
- Short circuit to ground and battery
- Enhanced diagnosis feedback via digital interface

### Functional safety features

- ISO 26262 safety element out of context for safety requirements up to ASIL D
- SPI interface with error detection (CRC, invalid read/write address, and SCLK count error detection)
- Communication watchdog
- Limp home mode and fail safe mode
- Monitoring of input pin status (IN and LHI)
- Current sense verification mode

**Table 1 Product summary**

| Parameter                                                      | Symbol            | Values         |
|----------------------------------------------------------------|-------------------|----------------|
| Power supply voltage range for normal operation                | $V_{S(NOR)}$      | 5 V to 20 V    |
| Extended power supply voltage range for operation              | $V_{S(EXT)}$      | 2.8 V to 28 V  |
| Digital supply voltage range for normal operation              | $V_{DD(NOR)}$     | 2.4 V to 5.5 V |
| Maximum digital supply current consumption in normal operation | $I_{VDD(NORMAL)}$ | 2.6 mA         |
| Typical operating current in active mode (all power stages ON) | $I_{GND(ACTIVE)}$ | 7.2 mA         |
| Typical operating current in idle mode (all power stages ON)   | $I_{GND(IDLE)}$   | 60 $\mu$ A     |
| Junction temperature range for normal operation                | $T_{J(NOR)}$      | -40°C to 150°C |
| Load dump voltage                                              | $V_{BAT(LD)}$     | 35 V           |

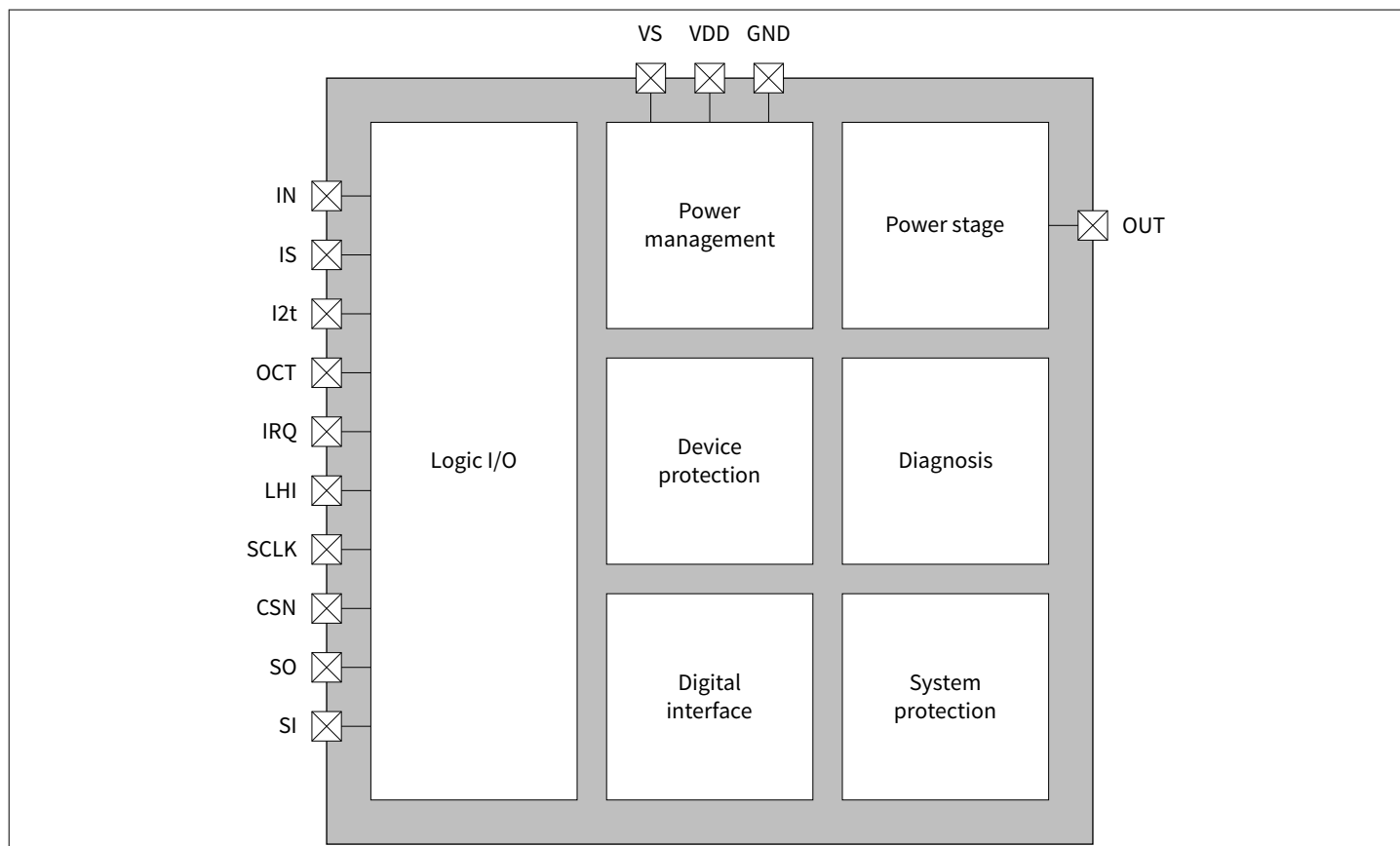
(table continues...)

**Table 1** (continued) Product summary

| Parameter                                                   | Symbol            | Values            |
|-------------------------------------------------------------|-------------------|-------------------|
| Typical thermal resistance junction-to-ambient              | $R_{th(JA)}$      | 24 K/W            |
| Maximum ON-state resistance ( $T_J = 150^{\circ}\text{C}$ ) | $R_{DS(ON)\_150}$ | 2.8 m $\Omega$    |
| Nominal load current ( $T_A = 85^{\circ}\text{C}$ )         | $I_{L(NOM)\_85}$  | 27.3 A            |
| Typical overcurrent detection threshold range               | $I_{L(OCT)}$      | 63.3 A to 176.5 A |

## 2 Block diagram and terms

### 2.1 Block diagram



**Figure 1** Block diagram

### 2.2 Terms

The figure below shows all the terms used in this datasheet, with their associated conventions for positive values. Voltages and currents are defined accordingly.

2 Block diagram and terms

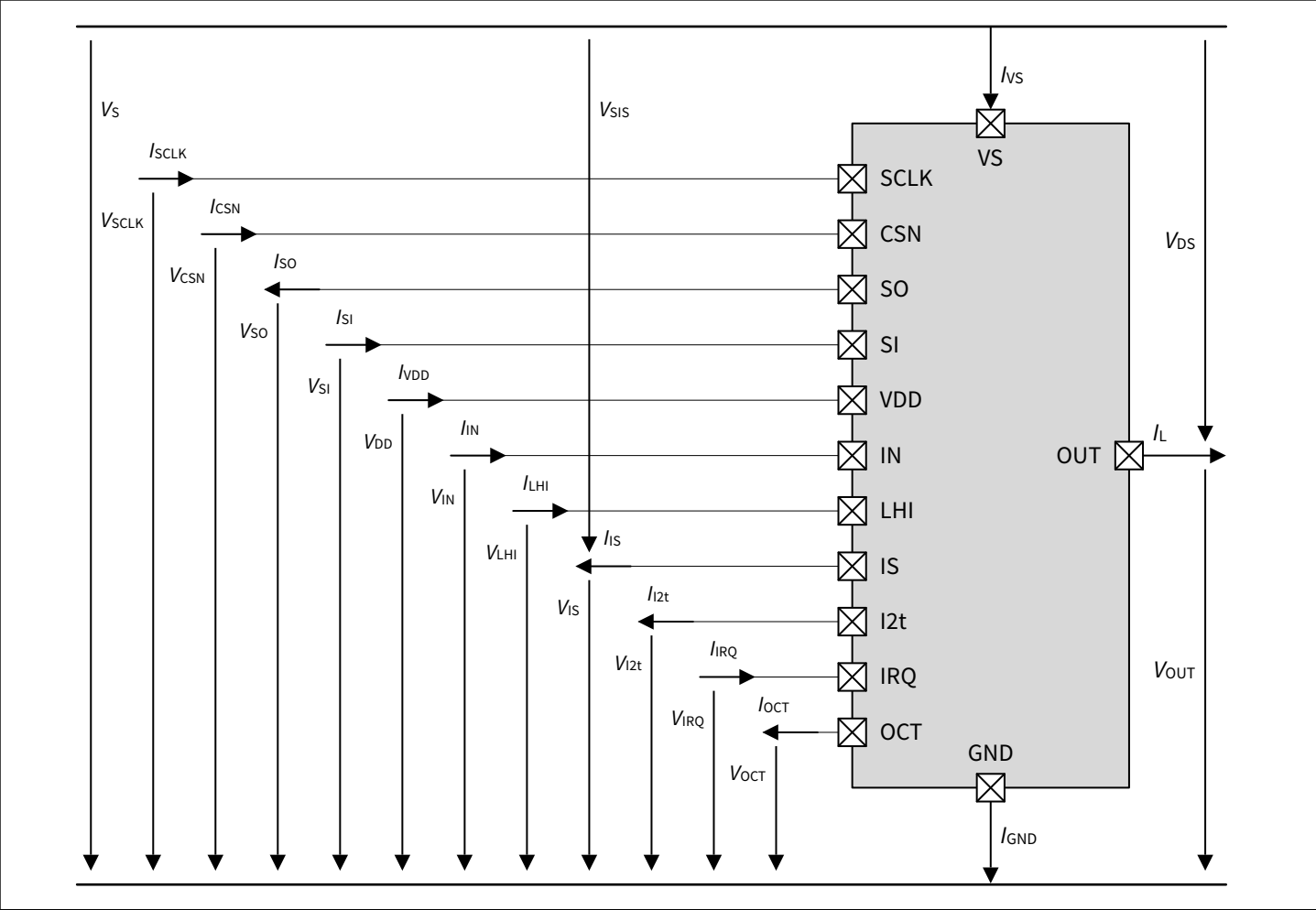


Figure 2 Voltage and current conventions

3 Pin configuration

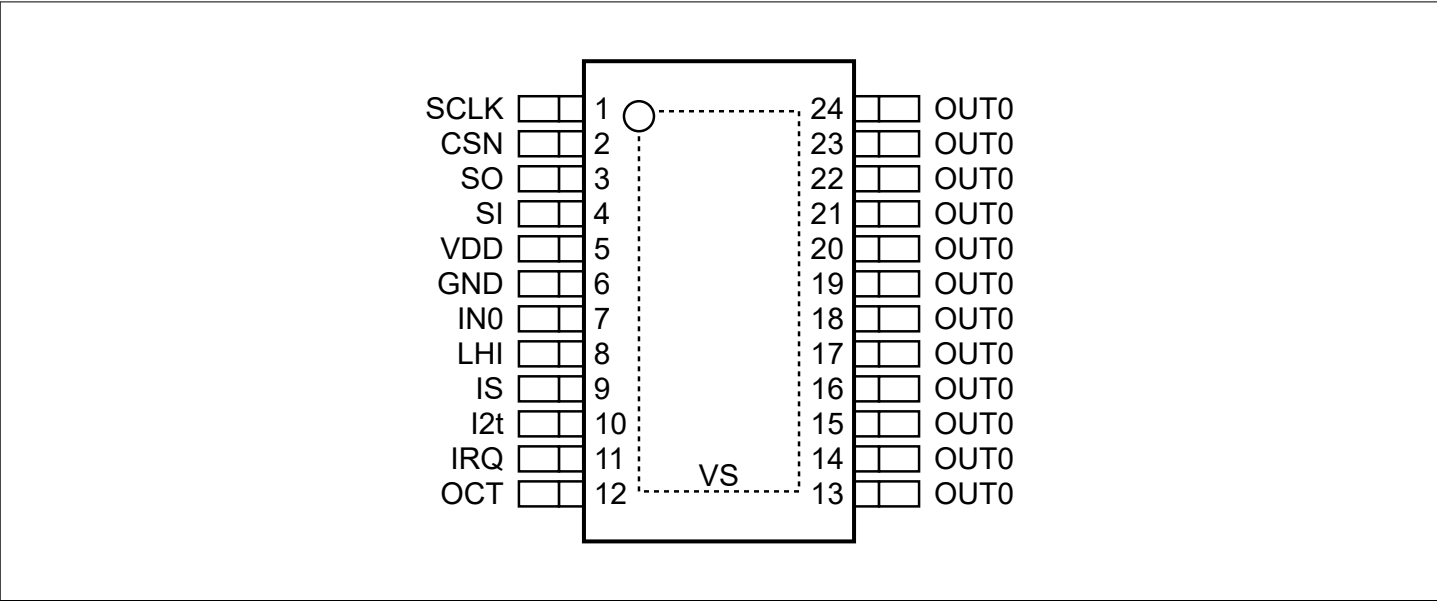


Figure 3 Pin configuration

Table 2 Pin definition

| Pin | Symbol              | I/O | Function                                                                                                                                                                                      |
|-----|---------------------|-----|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| EP  | VS<br>(exposed pad) | –   | <b>Power supply voltage</b><br>Battery voltage                                                                                                                                                |
| 1   | SCLK                | I   | <b>Serial clock</b><br>Serial clock of SPI interface (active HIGH)                                                                                                                            |
| 2   | CSN                 | I   | <b>Chip select</b><br>Chip select of SPI interface (active LOW); integrated pull up to VDD                                                                                                    |
| 3   | SO                  | O   | <b>Serial output</b><br>Serial output of SPI interface                                                                                                                                        |
| 4   | SI                  | I   | <b>Serial input</b><br>Serial input of SPI interface                                                                                                                                          |
| 5   | VDD                 | –   | <b>Digital supply voltage</b>                                                                                                                                                                 |
| 6   | GND                 | –   | <b>Ground</b><br>Ground connection for the internal logic                                                                                                                                     |
| 7   | IN0                 | I   | <b>Input</b><br>Digital signal to switch ON the power stage (active HIGH)<br>If not used: connect with $R_{IN} = 4.7\text{ k}\Omega$ resistor either to GND pin or to logic GND of the module |

(table continues...)

Table 2 (continued) Pin definition

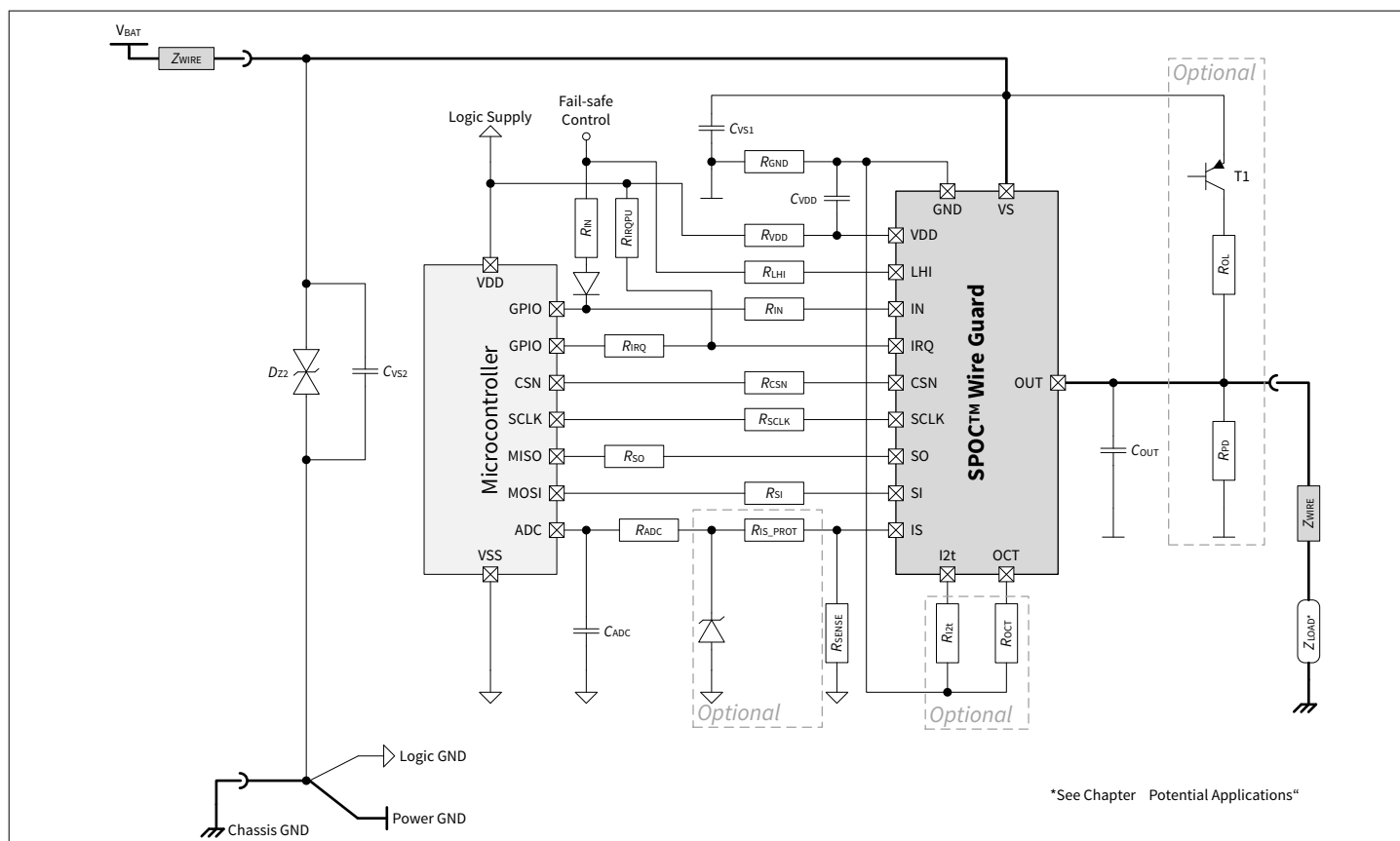
| Pin   | Symbol | I/O | Function                                                                                                                                                                                                                                                                    |
|-------|--------|-----|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 8     | LHI    | I   | <b>Limp home input</b><br>Digital signal to enter limp home mode (active HIGH)<br>If not used: connect with $R_{LHI} = 4.7 \text{ k}\Omega$ resistor either to GND pin or to logic GND of the module                                                                        |
| 9     | IS     | O   | <b>SENSE current output</b><br>Analog signal for diagnosis<br>If not used: leave open                                                                                                                                                                                       |
| 10    | I2t    | I   | <b>Selectable I2t protection curve</b><br>A resistor $R_{I2t}$ needs to be connected between I2t pin and GND pin to select one of the available I2t protection curves<br>If not used: leave open. I2t protection curve selection as described in the I2t protection chapter |
| 11    | IRQ    | O   | <b>Interruption request open drain output</b><br>Digital signal to inform the microcontroller of idle mode, warning, error or watchdog overflow (active HIGH)<br>If not used: connect with a $10 \text{ k}\Omega$ resistor either to GND pin or to logic GND of the module  |
| 12    | OCT    | I   | <b>Selectable overcurrent threshold</b><br>A resistor $R_{OCT}$ needs to be connected between OCT pin and GND pin to select one of the available overcurrent thresholds<br>If not used: leave open. Threshold selection as described in the overcurrent protection chapter  |
| 13-24 | OUT0   | O   | <b>Output</b><br>Protected high-side power stage output 0 <sup>1)</sup>                                                                                                                                                                                                     |

1) All output pins of the power stage have to be connected together on the PCB. All pins of the output are connected together internally. PCB traces have to be designed to withstand the maximum current that can flow.

## 4 Application information

**Note:** The information provided in this chapter is a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition, or quality of the device. The function must be verified in the real application. For sizing and dimensioning of external components, refer to the additional technical documentation or contact our technical support team for assistance.

### 4.1 Application setup



**Figure 4** Application diagram

### 4.2 External components

**Table 3** Suggested component values

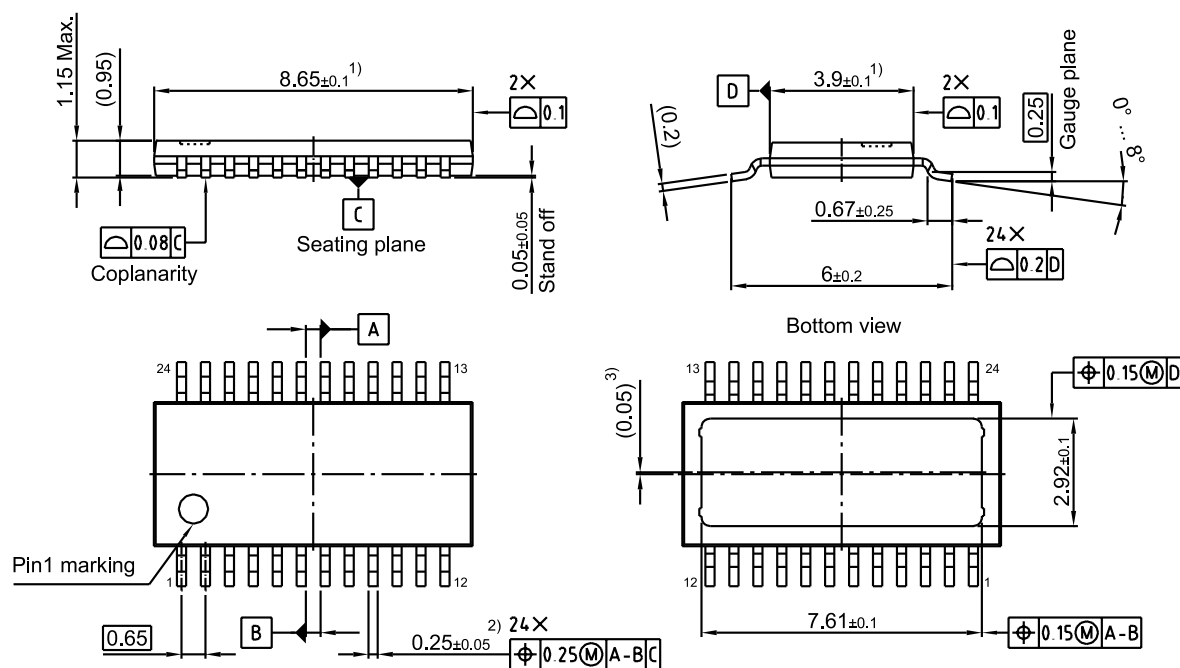
| Reference | Value                                                      | Purpose                                                                                                                                    |
|-----------|------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|
| $R_{GND}$ | 40.2 $\Omega$                                              | Ground voltage spikes filtering for improved robustness against battery voltage transients                                                 |
| $R_{VDD}$ | 150 $\Omega$ for VDD = 3.3 V<br>750 $\Omega$ for VDD = 5 V | Device logic protection                                                                                                                    |
| $R_{LHI}$ | 4.7 k $\Omega$                                             | Protection of the microcontroller during overvoltage and reverse polarity                                                                  |
| $R_{IN}$  | 4.7 k $\Omega$                                             | Protection of the microcontroller during overvoltage and reverse polarity<br>Necessary to switch OFF the power stage during loss of ground |

(table continues...)

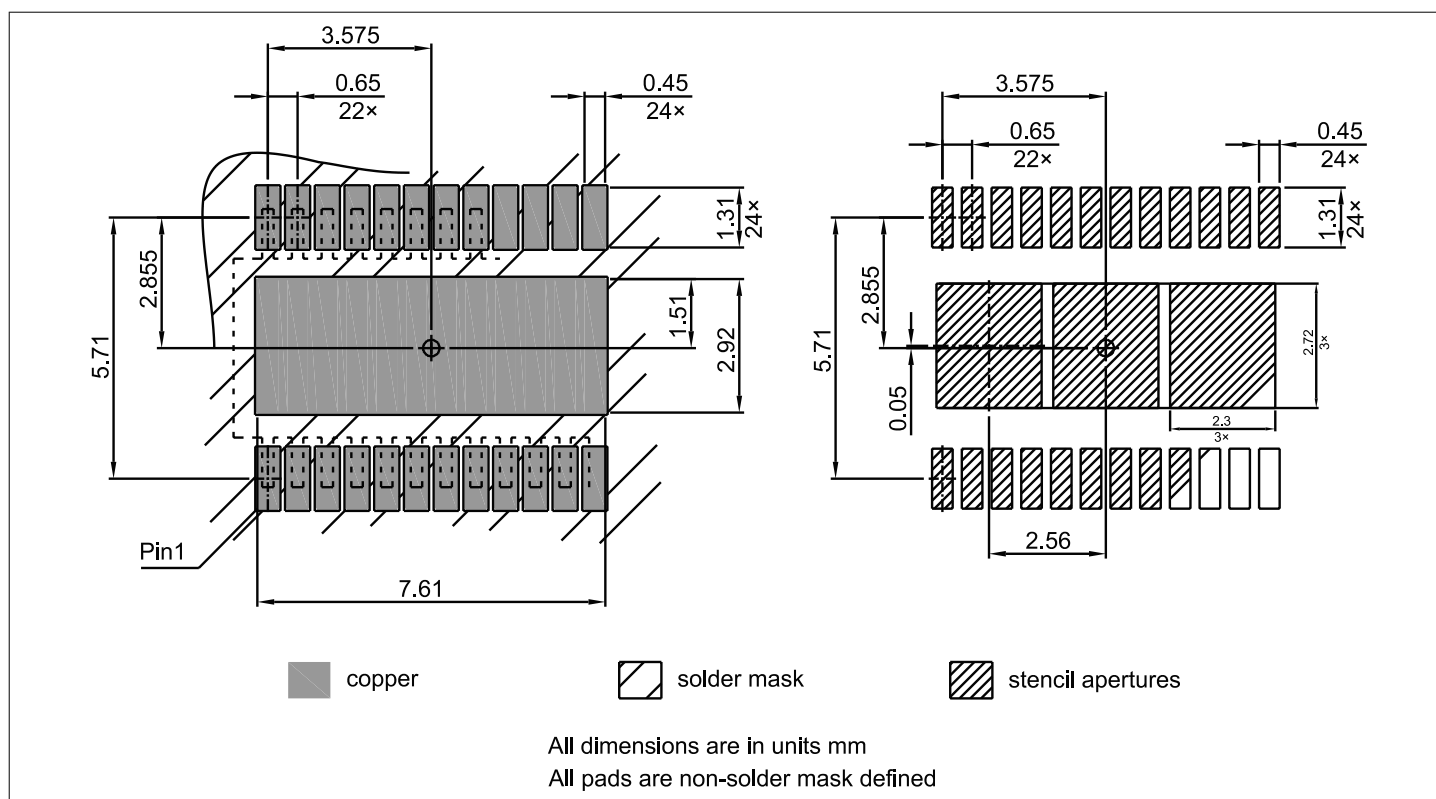
**Table 3** (continued) **Suggested component values**

| Reference       | Value                               | Purpose                                                                                                                                                                     |
|-----------------|-------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $R_{IRQ}$       | 4.7 k $\Omega$                      | Protection of the microcontroller during overvoltage and reverse polarity                                                                                                   |
| $R_{IRQP}$<br>U | 10 k $\Omega$                       | Interrupt request polarization (pull-up)<br>Ensure the polarization of the open drain IRQ pin for interrupt request at the microcontroller                                  |
| $R_{CSN}$       | 1.2 k $\Omega$                      | Protection of the microcontroller during overvoltage and reverse polarity                                                                                                   |
| $R_{SCLK}$      | 1.2 k $\Omega$                      | Protection of the microcontroller during overvoltage and reverse polarity                                                                                                   |
| $R_{SO}$        | 1.2 k $\Omega$                      | Protection of the microcontroller during overvoltage and reverse polarity                                                                                                   |
| $R_{SI}$        | 1.2 k $\Omega$                      | Protection of the microcontroller during overvoltage and reverse polarity                                                                                                   |
| $R_{IS\_PROT}$  | 4.7 k $\Omega$                      | Protection resistor for overvoltage, reverse polarity, and loss of ground<br>Value to be tuned with microcontroller specification                                           |
| $R_{SENSE}$     | 1.2 k $\Omega$                      | Sense resistor                                                                                                                                                              |
| $R_{ADC}$       | 4.7 k $\Omega$                      | Microcontroller ADC voltage spikes filtering                                                                                                                                |
| $R_{I2t}$       | $R_{I2t\_SHORT}$ to $R_{I2t\_OPEN}$ | Selection of the default I2t protection curve during power-up mode<br>Protection of the device during overvoltage and reverse polarity                                      |
| $R_{OCT}$       | $R_{OCT\_SHORT}$ to $R_{OCT\_OPEN}$ | Selection of the default overcurrent threshold high during power-up mode<br>Protection of the device during overvoltage and reverse polarity                                |
| $R_{OL}$        | 1.5 k $\Omega$                      | Output polarization (pull-up)<br>Ensure polarization of power stage during open load in OFF diagnosis                                                                       |
| $R_{PD}$        | 47 k $\Omega$                       | Output polarization (pull-down)<br>Ensure polarization of power stage to distinguish between open load and short to $V_S$ in OFF diagnosis                                  |
| $C_{ADC}$       | 220 pF                              | Microcontroller ADC voltage spikes filtering<br>A time constant $((R_{IS\_PROT} + R_{ADC}) * C_{ADC})$ longer than 1 $\mu$ s is recommended                                 |
| $C_{VDD}$       | 680 nF                              | Digital supply voltage spikes filtering and for improved robustness against battery voltage transients                                                                      |
| $C_{VS1}$       | 100 nF                              | Battery voltage spikes filtering                                                                                                                                            |
| $C_{VS2}$       | –                                   | Conditional buffer capacitor to support battery voltage spikes filtering in dependency of application setup (EMC)                                                           |
| $C_{OUT}$       | 10 nF                               | For improved electromagnetic compatibility (EMC)                                                                                                                            |
| $D_{Z1}$        | –                                   | Protection of microcontroller during overvoltage                                                                                                                            |
| $D_{Z2}$        | –                                   | Transient voltage suppressor diode<br>Protection against overvoltage, loss of battery while driving an inductive load, and voltage spikes caused by fast load disconnection |
| $T_1$           | –                                   | Switch the battery voltage for open load in OFF diagnosis                                                                                                                   |

## 5 Package information



**Figure 5 PG-TSDSO-24 package outlines**



**Figure 6** PG-TSDSO-24 footprint

**Note:** For minimum environmental impact and compliance with government regulations, the package of the device fulfills the requirements of a green product. Green products are RoHS-compliant (Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020). For further information, please refer to <https://www.infineon.com/packages>.



Revision history

| Revision  | Date of release | Description of changes                                                                                |
|-----------|-----------------|-------------------------------------------------------------------------------------------------------|
| Rev. 1.00 | 2026-03-03      | <a href="#">Table 1</a> updated<br><a href="#">Table 2</a> updated<br><a href="#">Table 3</a> updated |
| Rev. 0.10 | 2025-10-01      | Product overview available                                                                            |

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